

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

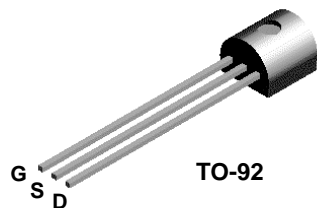
Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

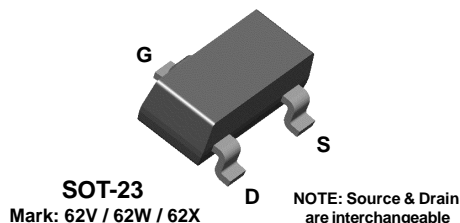
Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

**J210
J211
J212**



**MMBFJ210
MMBFJ211
MMBFJ212**



N-Channel RF Amplifier

This device is designed for HF/VHF mixer/amplifier and applications where Process 50 is not adequate. Sufficient gain and low noise for sensitive receivers. Sourced from Process 90.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{DG}	Drain-Gate Voltage	25	V
V _{GS}	Gate-Source Voltage	- 25	V
I _{GF}	Forward Gate Current	10	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max		Units
		J210-212	*MMBFJ210-212	
P _D	Total Device Dissipation Derate above 25°C	350 2.8	225 1.8	mW mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	125		°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	357	556	°C/W

*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

J210 / J211 / J212 / MMBFJ210 / MMBFJ211 / MMBFJ212

N-Channel RF Amplifier

(continued)

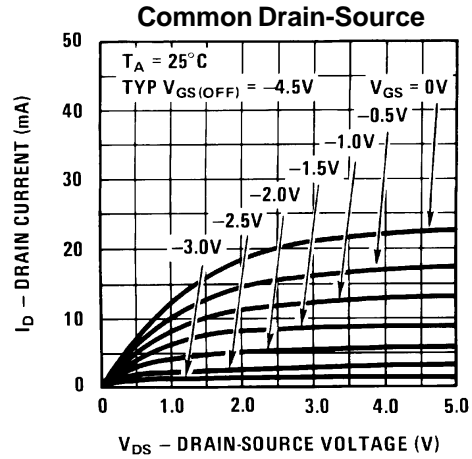
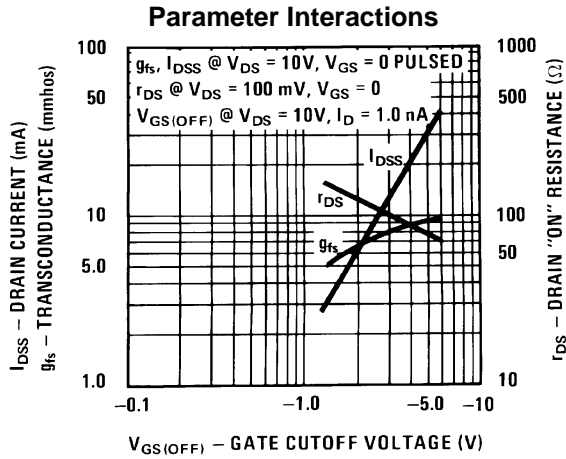
Electrical Characteristics

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHARACTERISTICS					
$V_{(BR)GSS}$	Gate-Source Breakdown Voltage	$I_G = 1.0 \mu A, V_{DS} = 0$	- 25		V
I_{GSS}	Gate Reverse Current	$V_{GS} = 15 V, V_{DS} = 0$		- 100	pA
$V_{GS(off)}$	Gate-Source Cutoff Voltage	$V_{DS} = 15 V, I_D = 1.0 nA$	210 211 212	-1.0 - 2.5 - 4.0	V V V
ON CHARACTERISTICS					
I_{DSS}	Zero-Gate Voltage Drain Current*	$V_{DS} = 15 V, V_{GS} = 0$	210 211 212	2.0 7.0 15	m A m A m A
SMALL SIGNAL CHARACTERISTICS					
g_{fs}	Common Source Forward Transconductance	$V_{DS} = 15 V, V_{GS} = 0, f = 1.0 kHz$	210 211 212	4000 6000 7000	$\mu mhos$ $\mu mhos$ $\mu mhos$
g_{oss}	Common Source Output Conductance	$V_{DS} = 15 V, V_{GS} = 0, f = 1.0 kHz$		200	$\mu mhos$

*Pulse Test: Pulse Width $\leq 300 \mu s$

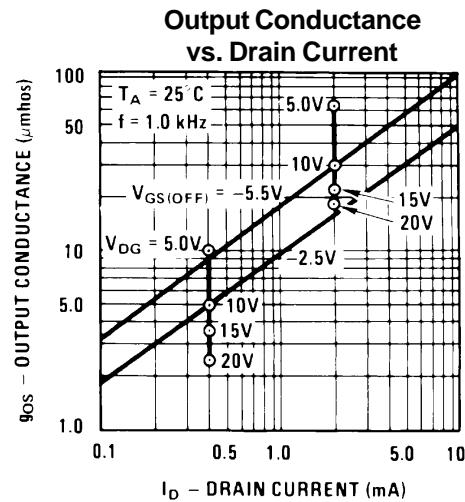
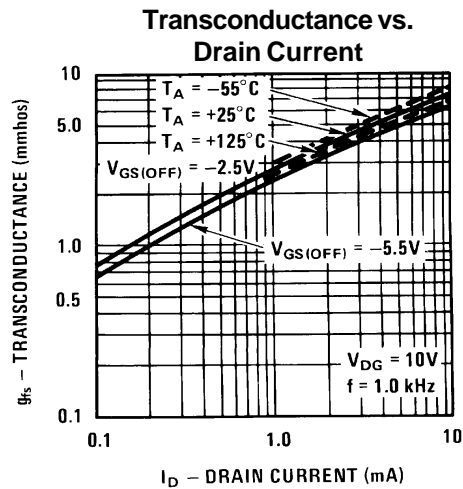
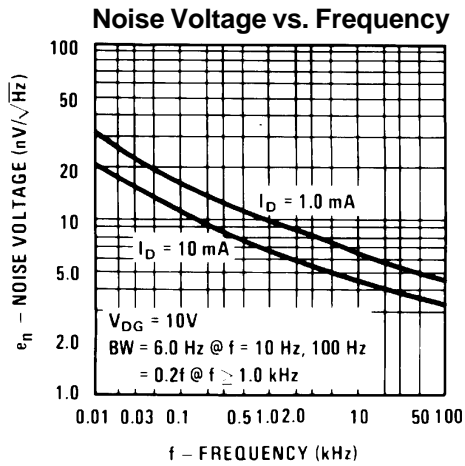
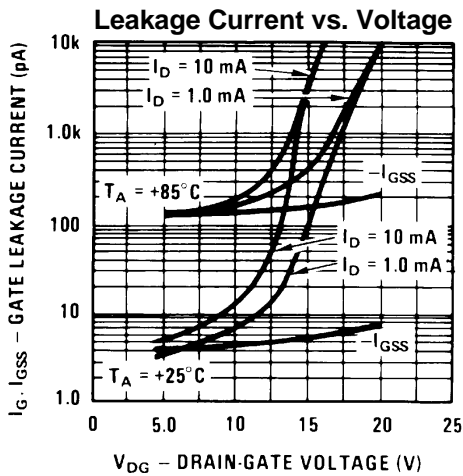
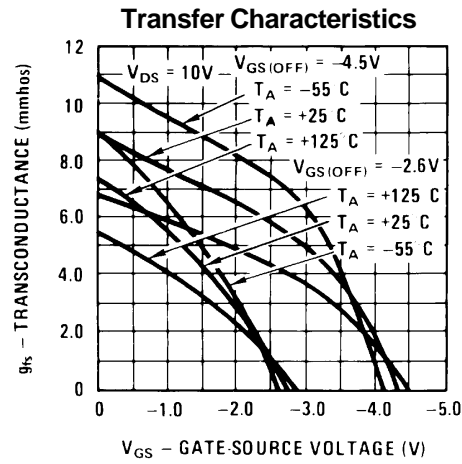
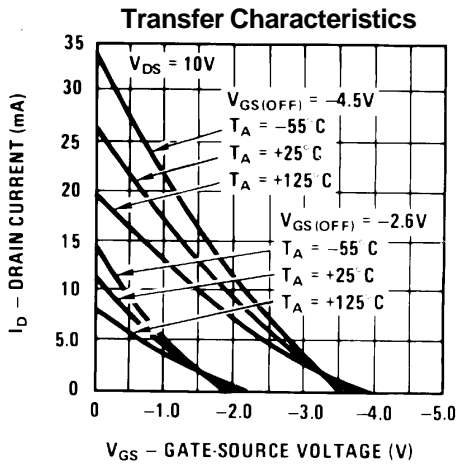
Typical Characteristics



J210 / J211 / J212 / MMBFJ210 / MMBFJ211 / MMBFJ212

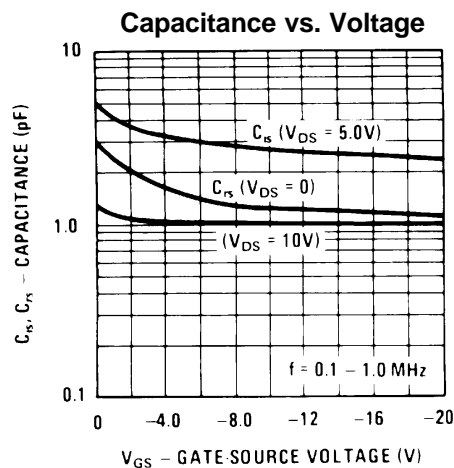
N-Channel RF Amplifier (continued)

Typical Characteristics (continued)

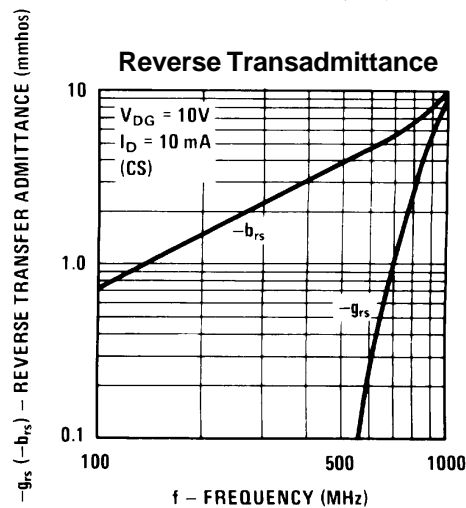
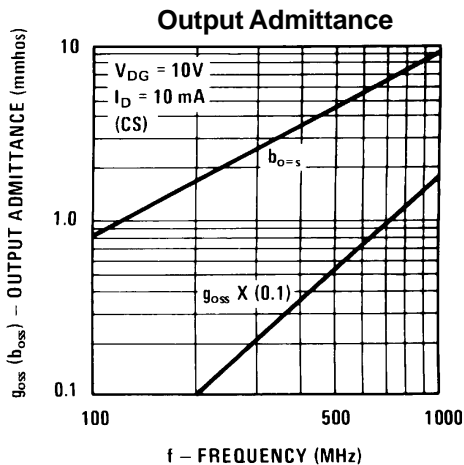
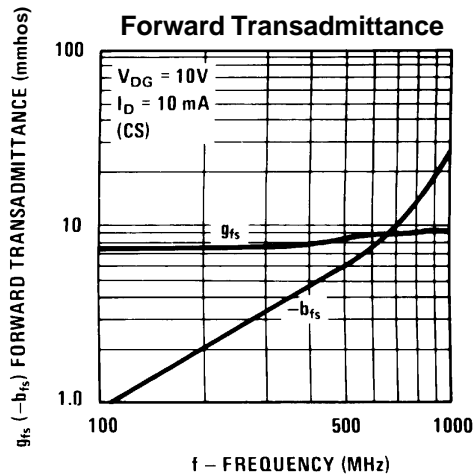
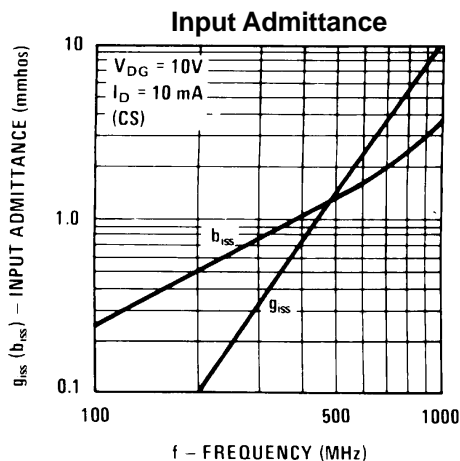


J210 / J211 / J212 / MMBFJ210 / MMBFJ211 / MMBFJ212

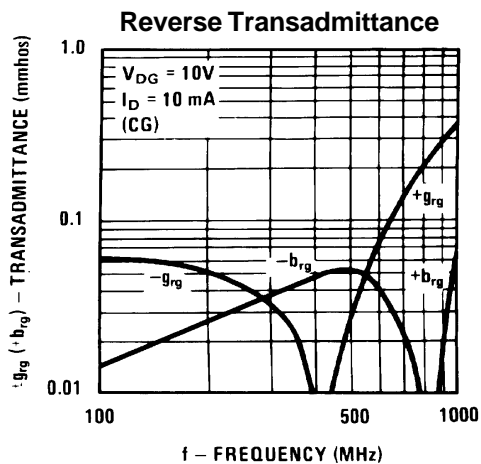
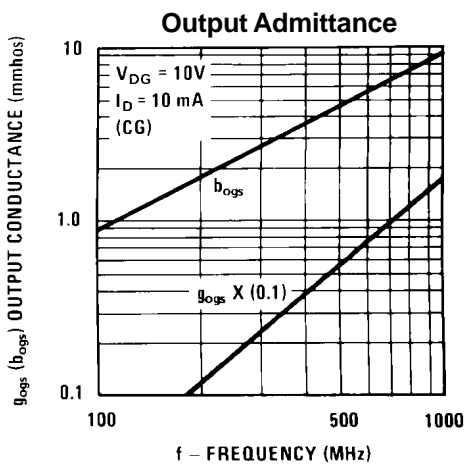
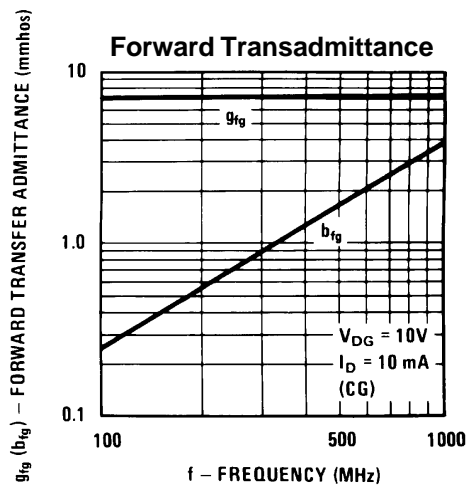
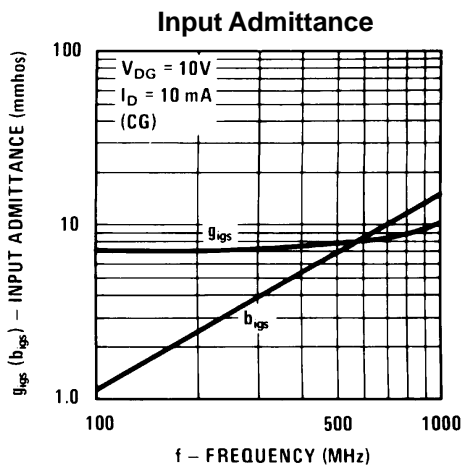
Typical Characteristics (continued)



Common Source Characteristics



Common Gate Characteristics



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CoolFET TM	FRFET TM	POP TM	SuperSOT TM -8
CROSSVOLT TM	GlobalOptoisolator TM	PowerTrench [®]	SyncFET TM
DenseTrench TM	GTO TM	QFET TM	TinyLogic TM
DOMET TM	HiSeC TM	QS TM	UHC TM
EcoSPARK TM	ISOPLANAR TM	QT Optoelectronics TM	UltraFET [®]
E ² CMOS TM	LittleFET TM	Quiet Series TM	VCX TM
EnSigna TM	MicroFET TM	SILENT SWITCHER [®]	
FACT TM	MICROWIRE TM	SMART START TM	
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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.